# DSA5G01

### Silicon NPN epitaxial planar type

For high-frequency amplification DSA2G01 in SMini3 type package

#### Features

- $\bullet$  High forward current transfer ratio  $h_{FE}$  with excellent linearity
- $\bullet$  High transition frequency  $f_{T}$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

#### Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-30	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-20	V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-30	mA
Collector power dissipation	P <sub>C</sub>	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Base-emitter voltage	$V_{BE}$	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}$		- 0.7		V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = -10 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{\rm CE} = -20$ V, $I_{\rm B} = 0$			-100	μΑ
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{\rm EB} = -5 \text{ V}, I_{\rm C} = 0$			-10	μΑ
Forward current transfer ratio *	$\mathbf{h}_{\mathrm{FE}}$	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}$	70		220	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -1 \text{ mA}$		- 0.1		V
Transition frequency	$\mathbf{f}_{\mathrm{T}}$	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}$	150	300		MHz
Reverse transfer capacitance (Common emitter)	C <sub>re</sub>	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 10.7 \text{ MHz}$		1.0		pF
Noise figure	NF	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 5 \text{ MHz}$		2.8		dB
Reverse transfer impedance	Z <sub>rb</sub>	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 2 \text{ MHz}$		22		Ω

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Code	В	С	0
Rank	В	С	No-rank
h <sub>FE</sub>	70 to 140	110 to 220	70 to 220
Marking Symbol	A4B	A4C	A4

Product of no-rank is not classified and have no marking symbol for rank.

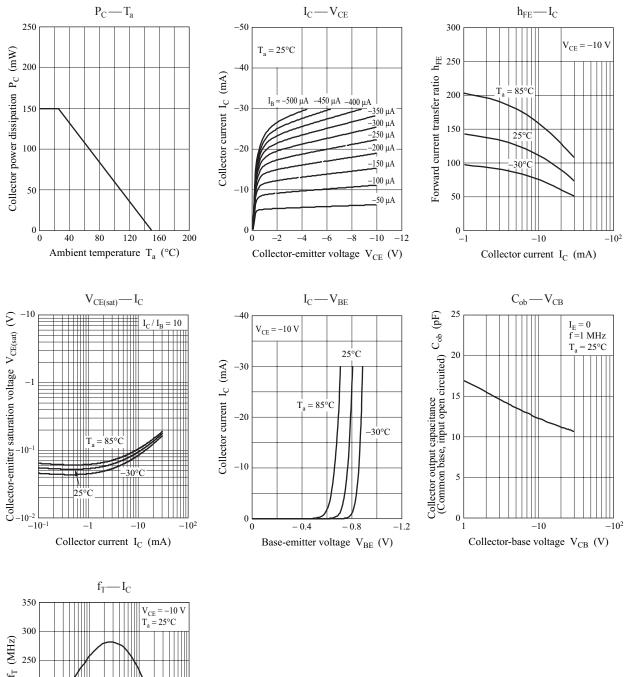
#### Package

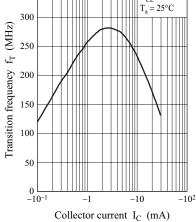
- Code
- SMini3-F2-B
- Pin Name
  - 1. Base
  - 2. Emitter
  - 3. Collector

Marking Symbol: A4

#### DSA5G01

### **Panasonic**

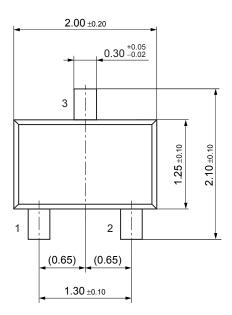


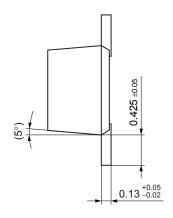


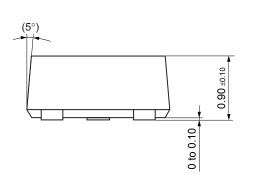
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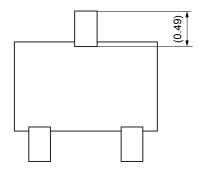
### SMini3-F2-B

Unit: mm









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